# NSN 5961-00-140-0243

Transistor - Page 1 of 1



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**Inclosure Material:** 

Metal

**Overall Length:** 

0.450 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

55.0 breakdown voltage, collector-to-base, emitter open and 12.0 breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 7.00 amperes source cutoff current and 15.00 amperes source cutoff current

## Power Rating Per Characteristic:

117.0 watts small-signal input power, common-collector

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

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